

### GENERAL DESCRIPTION

The 84427 is a Crystal-to-LVDS Frequency Synthesizer/Fanout Buffer. The output frequency can be programmed using the frequency select pins. The low phase noise characteristics of the 84427 make it an ideal clock source for 10 Gigabit Ethernet, 10 Gigabit Fibre Channel, OC3 and OC12 applications.

### FEATURES

- Six LVDS outputs
- Crystal oscillator interface
- Output frequency range: 77.76MHz to 625MHz
- Crystal input frequency: 19.44MHz, 25MHz or 25.5MHz
- RMS phase jitter at 155.52MHz, using a 19.44MHz crystal (12kHz to 20MHz): 3.4ps (typical)

Phase noise:

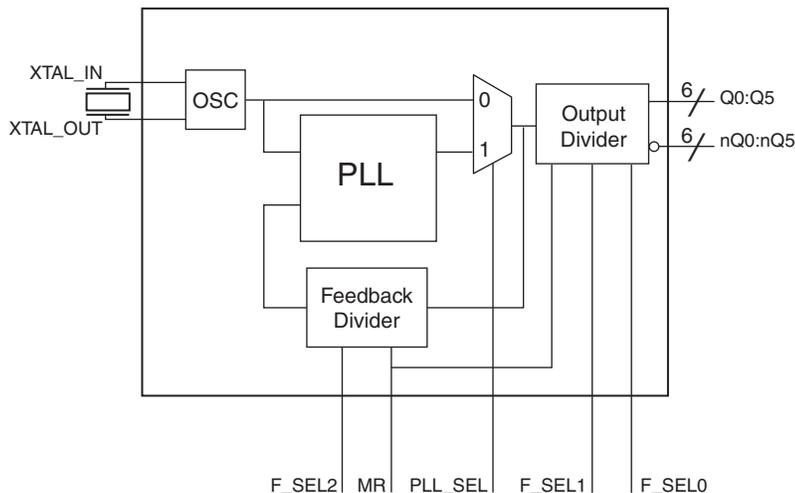
Offset	Noise Power
100Hz	-95 dBc/Hz
1kHz	-110 dBc/Hz
10kHz	-120 dBc/Hz
100kHz	-121 dBc/Hz

- 3.3V supply voltage
- 0°C to 70°C ambient operating temperature
- Available in lead-free RoHS-compliant package

FUNCTION TABLE

Inputs					Output Frequency
F_XTAL	MR	F_SEL2	F_SEL1	F_SELO	F_OUT
X	1	X	X	X	LOW
19.44MHz	0	1	0	0	77.76MHz
19.44MHz	0	1	0	1	155.52MHz
19.44MHz	0	1	1	0	311.04MHz
19.44MHz	0	1	1	1	622.08MHz
25MHz	0	0	0	0	78.125MHz
25MHz	0	0	0	1	156.25MHz
25MHz	0	0	1	0	312.5 MHz
25MHz	0	0	1	1	625MHz
25.5MHz	0	0	0	1	159.375MHz

### BLOCK DIAGRAM



### PIN ASSIGNMENT

Q0	1	24	V <sub>DD</sub>
nQ0	2	23	F_SEL0
Q1	3	22	F_SEL1
nQ1	4	21	MR
Q2	5	20	XTAL_IN
nQ2	6	19	XTAL_OUT
Q3	7	18	F_SEL2
nQ3	8	17	V <sub>DDA</sub>
Q4	9	16	V <sub>DD</sub>
nQ4	10	15	PLL_SEL
Q5	11	14	GND
nQ5	12	13	V <sub>DD</sub>

**84427**  
**24-Lead, 300-MIL SOIC**  
 7.5mm x 15.33mm x 2.3mm body package  
**M Package**  
 Top View

TABLE 1. PIN DESCRIPTIONS

Number	Name	Type		Description
1, 2	Q0, nQ0	Output		Differential output pair. LVDS interface levels.
3, 4	Q1, nQ1	Output		Differential output pair. LVDS interface levels.
5, 6	Q2, nQ2	Output		Differential output pair. LVDS interface levels.
7, 8	Q3, nQ3	Output		Differential output pair. LVDS interface levels.
9, 10	Q4, nQ4	Output		Differential output pair. LVDS interface levels.
11, 12	Q5, nQ5	Output		Differential output pair. LVDS interface levels.
13, 16, 24	V <sub>DD</sub>	Power		Core supply pins.
14	GND			Power supply ground.
15	PLL_SEL	Input	Pullup	Selects between the PLL and crystal inputs as the input to the dividers. When HIGH, selects PLL. When LOW, selects XTAL_IN and XTAL_OUT. LVCMOS / LVTTTL interface levels.
17	V <sub>DDA</sub>	Power		Analog supply pin.
18	F_SEL2	Input	Pullup	Feedback frequency select pin. LVCMOS/LVTTTL interface levels.
19, 20	XTAL_OUT, XTAL_IN	Input		Crystal oscillator interface. XTAL_IN is the input, XTAL_OUT is the output.
21	MR	Input	Pulldown	Active High Master Reset. When logic HIGH, the internal dividers are reset causing the true outputs Qx to go low and the inverted outputs nQx to go high. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS / LVTTTL interface levels.
22	F_SEL1	Input	Pulldown	Output frequency select pin. LVCMOS/LVTTTL interface levels.
23	F_SELO	Input	Pullup	Output frequency select pin. LVCMOS/LVTTTL interface levels.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, $V_{DD}$	4.6V
Inputs, $V_I$	-0.5V to $V_{DD} + 0.5V$
Outputs, $I_O$	
Continuous Current	10mA
Surge Current	15mA
Package Thermal Impedance, $\theta_{JA}$	50°C/W (0 lfpm)
Storage Temperature, $T_{STG}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

**TABLE 3A. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		$V_{DD} - 0.72$	3.3	$V_{DD}$	V
$I_{DD}$	Power Supply Current				300	mA
$I_{DDA}$	Analog Supply Current				30	mA

**TABLE 3B. LVCMOS / LVTTTL DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage		2		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage		-0.3		0.8	V
$I_{IH}$	Input High Current	MR, F_SEL1	$V_{DD} = V_{IN} = 3.465V$		150	$\mu A$
		PLL_SEL, F_SEL0, F_SEL2	$V_{DD} = V_{IN} = 3.465V$		5	$\mu A$
$I_{IL}$	Input Low Current	MR, F_SEL1	$V_{DD} = 3.465V, V_{IN} = 0V$	-5		$\mu A$
		PLL_SEL, F_SEL0, F_SEL2	$V_{DD} = 3.465V, V_{IN} = 0V$	-150		$\mu A$

**TABLE 3C. LVDS DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{OD}$	Differential Output Voltage		375	475	575	mV
$\Delta V_{OD}$	$V_{OD}$ Magnitude Change				50	mV
$V_{OS}$	Offset Voltage		1.3	1.45	1.6	V
$\Delta V_{OS}$	$V_{OS}$ Magnitude Change				50	mV

TABLE 4. CRYSTAL CHARACTERISTICS

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		19.44		25.5	MHz
Equivalent Series Resistance (ESR)				50	$\Omega$
Shunt Capacitance				7	pF
Drive Level				1	mW

TABLE 5. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$F_{OUT}$	Output Frequency		77.76		625	MHz
$t_{jit}(\emptyset)$	RMS Phase Jitter (Random); NOTE 1	155.52MHz, (Integration Range: 12kHz-20MHz)		3.4		ps
		156.25MHz, (Integration Range: 12kHz-20MHz)		3.1		ps
$t_{jit}(cc)$	Cycle-to-Cycle Jitter; NOTE 2				36	ps
$t_{sk}(o)$	Output Skew; NOTE 3, 4				85	ps
$t_{R}/t_{F}$	Output Rise/Fall Time	20% to 80%	200		600	ps
odc	Output Duty Cycle		47		52	%
$t_{LOCK}$	PLL Lock Time				1	ms

See Parameter Measurement Information section.

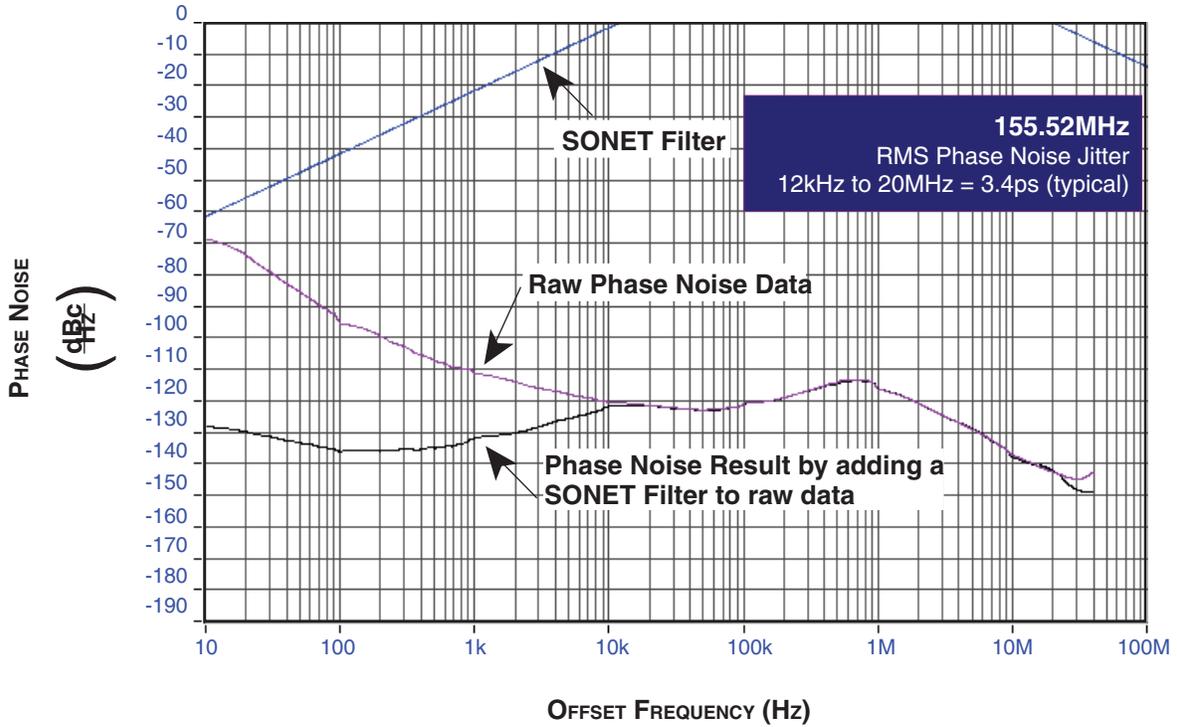
NOTE 1: See Phase Noise Plots.

NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.

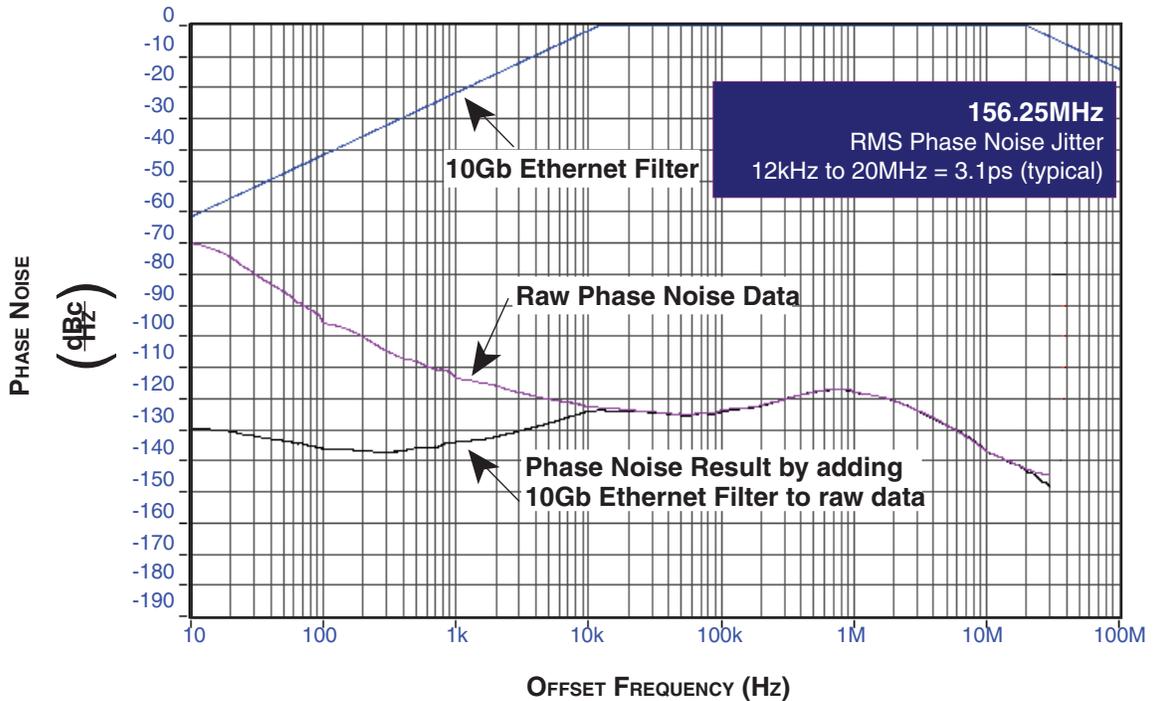
NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential crossing points.

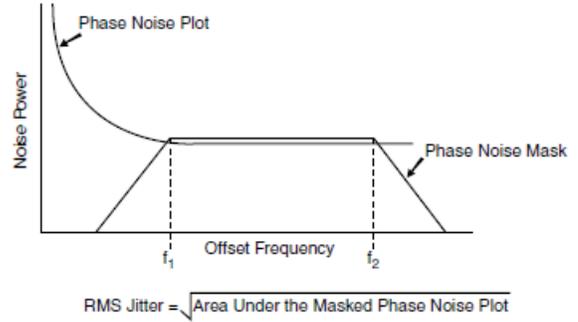
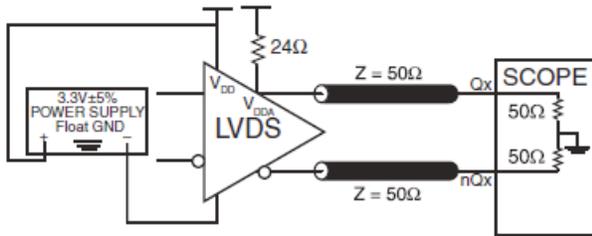
**TYPICAL PHASE NOISE AT 155.52MHz**



**TYPICAL PHASE NOISE AT 156.25MHz**

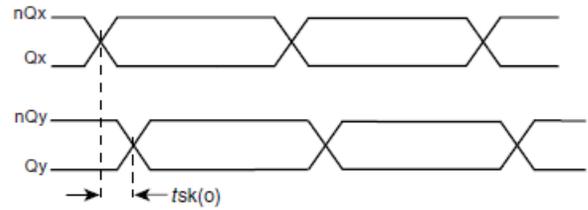
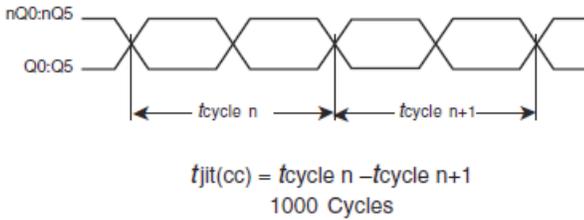


## PARAMETER MEASUREMENT INFORMATION



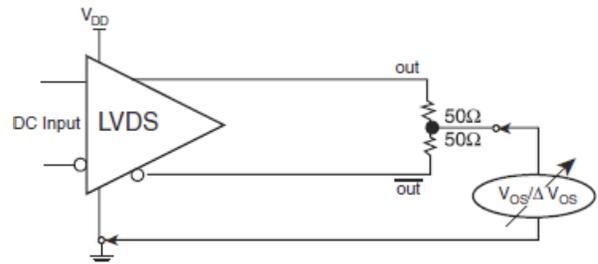
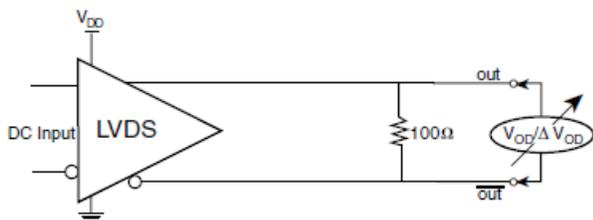
**3.3V OUTPUT LOAD AC TEST CIRCUIT**

**RMS PHASE JITTER**



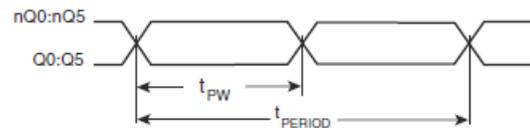
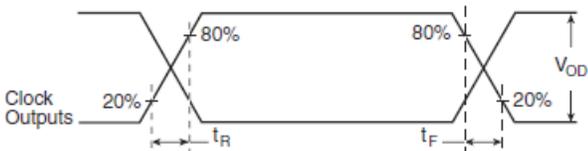
**CYCLE-TO-CYCLE JITTER**

**OUTPUT SKEW**



**DIFFERENTIAL OUTPUT VOLTAGE SETUP**

**OFFSET VOLTAGE SETUP**



$$odc = \frac{t_{PW}}{t_{PERIOD}} \times 100\%$$

**OUTPUT RISE/FALL TIME**

**OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD**

## APPLICATION INFORMATION

### POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The 84427 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$  and  $V_{DDA}$  should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a  $24\Omega$  resistor along with a  $10\mu\text{F}$  and a  $.01\mu\text{F}$  bypass capacitor should be connected to each  $V_{DDA}$  pin.

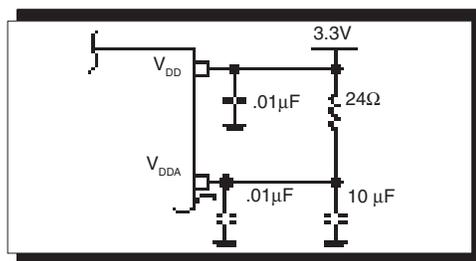


FIGURE 1. POWER SUPPLY FILTERING

### CRYSTAL INPUT INTERFACE

The 84427 has been characterized with  $18\text{pF}$  parallel resonant crystals. The capacitor values,  $C1$  and  $C2$ , shown in *Figure 2* below were determined using an  $18\text{pF}$  parallel resonant crystal

and were chosen to minimize the ppm error. The optimum  $C1$  and  $C2$  values can be slightly adjusted for different board layouts.

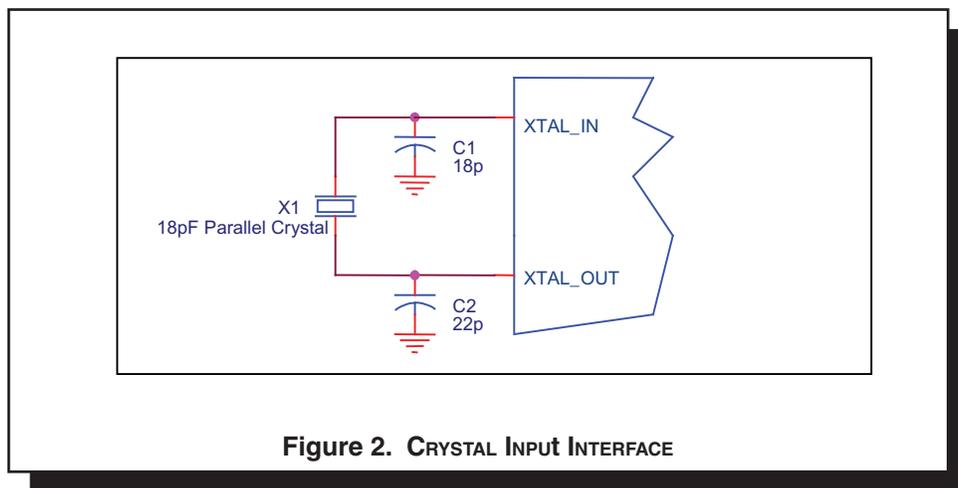


Figure 2. CRYSTAL INPUT INTERFACE

## LVC MOS TO XTAL INTERFACE

The XTAL\_IN input can accept a single-ended LVC MOS signal through an AC coupling capacitor. A general interface diagram is shown in *Figure 3*. The XTAL\_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVC MOS inputs, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires

that the output impedance of the driver ( $R_o$ ) plus the series resistance ( $R_s$ ) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First,  $R_1$  and  $R_2$  in parallel should equal the transmission line impedance. For most  $50\Omega$  applications,  $R_1$  and  $R_2$  can be  $100\Omega$ . This can also be accomplished by removing  $R_1$  and making  $R_2$   $50\Omega$ .

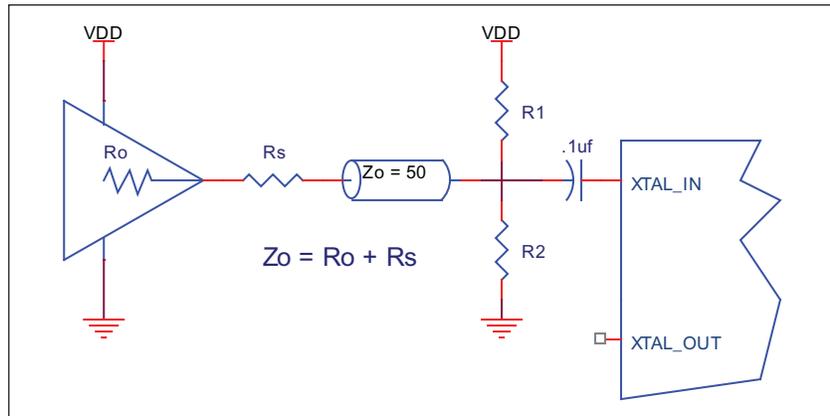


FIGURE 3. GENERAL DIAGRAM FOR LVC MOS DRIVER TO XTAL INPUT INTERFACE

## RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

### OUTPUTS:

#### LVDS

All unused LVDS output pairs can be either left floating or terminated with  $100\Omega$  across. If they are left floating, we recommend that there is no trace attached.

### LVDS DRIVER TERMINATION

A general LVDS interface is shown in *Figure 4*. In a 100Ω differential transmission line environment, LVDS drivers require a matched load termination of 100Ω across near the receiver

input. For a multiple LVDS outputs buffer, if only partial outputs are used, it is recommended to terminate the un-used outputs.

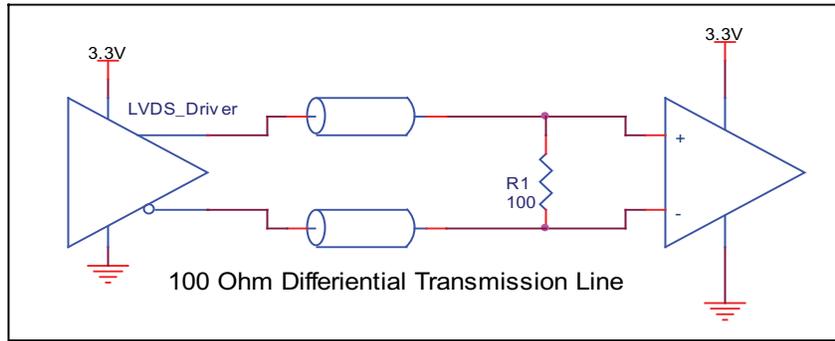


FIGURE 4. TYPICAL LVDS DRIVER TERMINATION

### SCHEMATIC EXAMPLE

Figure 5A shows a schematic example of using an 84427. In this example, the input is a 25MHz parallel resonant crystal with load capacitor CL=18pF. The frequency fine tuning capacitors C1 and C2 is 22pF and 18pF respectively. This example also shows logic control input handling. The configuration is set at F\_SEL[2:0]=101, therefore, the output frequency is 156.25MHz.

It is recommended to have one decouple capacitor per power pin. Each decoupling capacitor should be located as close as possible to the power pin. The low pass filter R7, C11 and C16 for clean analog supply should also be located as close to the V<sub>D</sub> pin as possible.

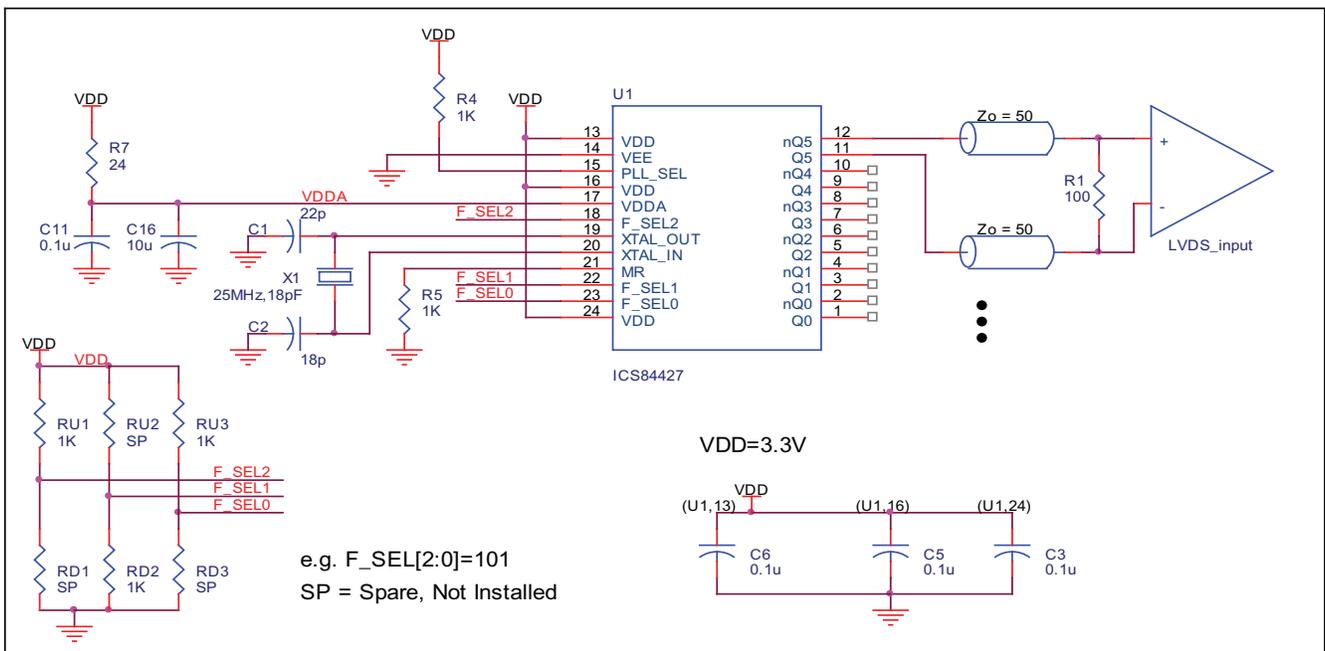


FIGURE 5A. 84427 SCHEMATIC EXAMPLE

The following component footprints are used in this layout example:

All the resistors and capacitors are size 0603.

#### POWER AND GROUNDING

Place the decoupling capacitors C3, C5 and C6, as close as possible to the power pins. If space allows, placement of the decoupling capacitor on the component side is preferred. This can reduce unwanted inductance between the decoupling capacitor and the power pin caused by the via.

Maximize the power and ground pad sizes and number of vias capacitors. This can reduce the inductance between the power and ground planes and the component power and ground pins.

The RC filter consisting of R7, C11, and C16 should be placed as close to the  $V_{DDA}$  pin as possible.

#### CLOCK TRACES AND TERMINATION

Poor signal integrity can degrade the system performance or cause system failure. In synchronous high-speed digital systems, the clock signal is less tolerant to poor signal integrity than other signals. Any ringing on the rising or falling edge or excessive ring back can cause system failure. The shape of the trace and the trace delay might be restricted by the available space on the board and the component location. While routing the traces, the clock signal traces should be routed first and should be locked prior to routing other signal traces.

- The differential 100 $\Omega$  output traces should have the same length.
- Avoid sharp angles on the clock trace. Sharp angle turns cause the characteristic impedance to change on the transmission lines.
- Keep the clock traces on the same layer. Whenever possible, avoid placing vias on the clock traces. Placement of vias on the traces can affect the trace characteristic impedance and hence degrade signal integrity.
- To prevent cross talk, avoid routing other signal traces in parallel with the clock traces. If running parallel traces is unavoidable, allow a separation of at least three trace widths between the differential clock trace and the other signal trace.
- Make sure no other signal traces are routed between the clock trace pair.
- The matching termination resistors should be located as close to the receiver input pins as possible.

#### CRYSTAL

The crystal X1 should be located as close as possible to the pins 20 (XTAL\_IN) and 19 (XTAL\_OUT). The trace length between the X1 and U1 should be kept to a minimum to avoid unwanted parasitic inductance and capacitance. Other signal traces should not be routed near the crystal traces.

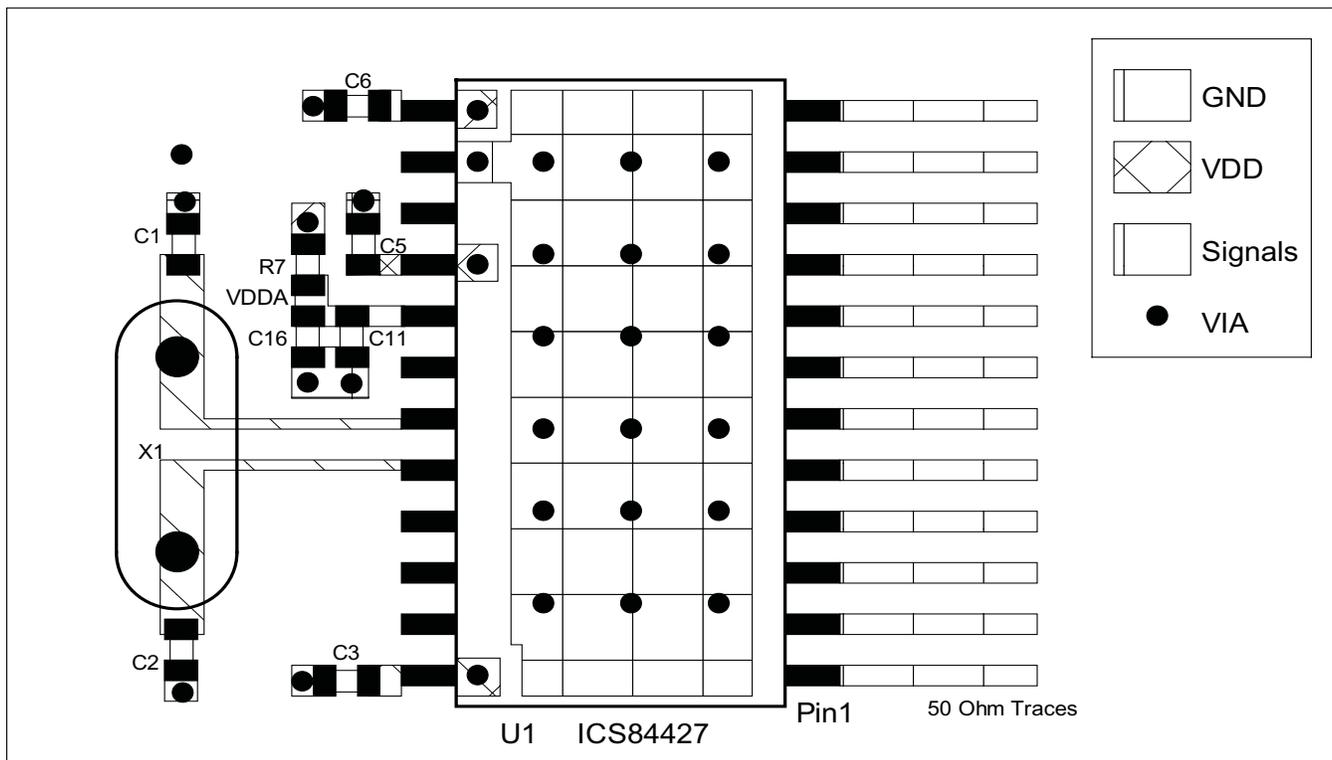


FIGURE 5B. PCB BOARD LAYOUT FOR 84427

## POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the 84427. Equations and example calculations are also provided.

### 1. Power Dissipation.

The total power dissipation for the 84427 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for  $V_{DD} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

- Power (core)<sub>MAX</sub> =  $V_{DD\_MAX} * (I_{DD\_MAX} + I_{DDA\_MAX}) = 3.465V * (300mA + 30mA) = \mathbf{1143.45mW}$

### 2. Junction Temperature.

Junction temperature,  $T_j$ , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for the devices is 125°C.

The equation for  $T_j$  is as follows:  $T_j = \theta_{JA} * Pd\_total + T_A$

$T_j$  = Junction Temperature

$\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

$Pd\_total$  = Total Device Power Dissipation (example calculation is in section 1 above)

$T_A$  = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 43°C/W per Table 6 below.

Therefore,  $T_j$  for an ambient temperature of 70°C with all outputs switching is:

$$70^\circ\text{C} + 1.143\text{W} * 43^\circ\text{C/W} = 119.1^\circ\text{C}. \text{ This is below the limit of } 125^\circ\text{C}.$$

This calculation is only an example.  $T_j$  will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

**TABLE 6. THERMAL RESISTANCE  $\theta_{JA}$  FOR 24-PIN SOIC, FORCED CONVECTION**

$\theta_{JA}$ by Velocity (Linear Feet per Minute)			
	0	200	500
Multi-Layer PCB, JEDEC Standard Test Boards	50°C/W	43°C/W	38°C/W
<b>NOTE:</b> Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.			

## RELIABILITY INFORMATION

**TABLE 7.  $\theta_{JA}$  VS. AIR FLOW TABLE FOR 24 LEAD SOIC**

$\theta_{JA}$ by Velocity (Linear Feet per Minute)			
	<b>0</b>	<b>200</b>	<b>500</b>
Multi-Layer PCB, JEDEC Standard Test Boards	50°C/W	43°C/W	38°C/W

**NOTE:** Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

### TRANSISTOR COUNT

The transistor count for 84427 is: 2804

PACKAGE OUTLINE - M SUFFIX FOR 24 LEAD SOIC

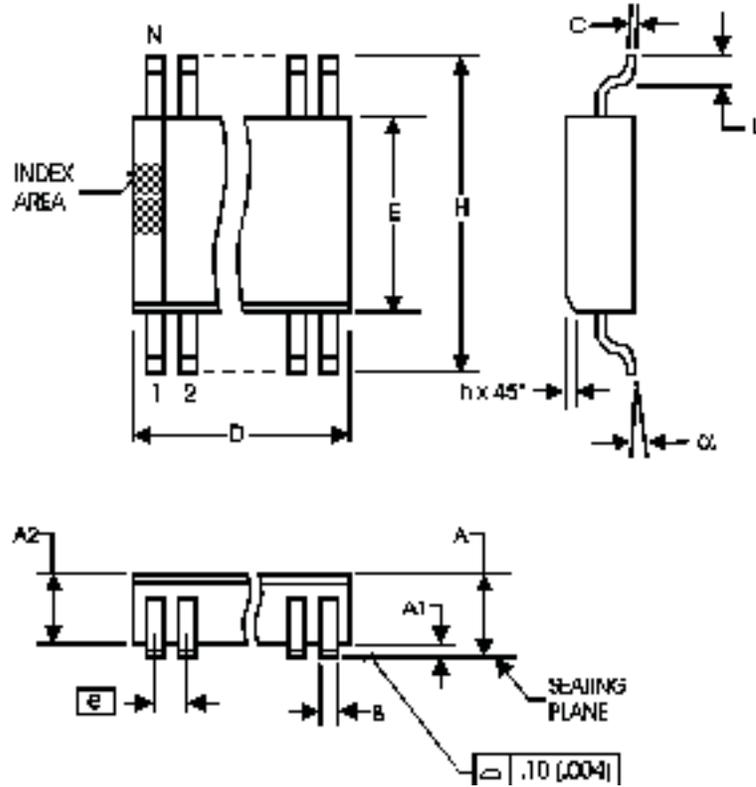


TABLE 8. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	Minimum	Maximum
N	24	
A	--	2.65
A1	0.10	--
A2	2.05	2.55
B	0.33	0.51
C	0.18	0.32
D	15.20	15.85
E	7.40	7.60
e	1.27 BASIC	
H	10.00	10.65
h	0.25	0.75
L	0.40	1.27
alpha	0°	8°

Reference Document: JEDEC Publication 95, MS-013, MO-119

**TABLE 9. ORDERING INFORMATION**

<b>Part/Order Number</b>	<b>Marking</b>	<b>Package</b>	<b>Shipping Packaging</b>	<b>Temperature</b>
84427CMLF	ICS84427CMLF	24 Lead "Lead-Free" SOIC	tube	0°C to 70°C
84427CMLFT	ICS84427CMLF	24 Lead "Lead-Free" SOIC	tape & reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

REVISION HISTORY SHEET				
Rev	Table	Page	Description of Change	Date
B	T9	14 16	Updated datasheet's header/footer with IDT from ICS. Removed ICS prefix from Part/Order Number column.Added Contact Page.	7/27/10
B	T9	1 14	Product Discontinuation Notice - PDN CQ-15-03. Ordering Information - removed leaded devices.	5/6/15



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